NSN 5961-01-238-2344

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-238-2344 **Inclosure Material:** Ceramic **Overall Length:** 7.677 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 1000.0 repetitive peak reverse voltage and 700.0 nonrepetitive peak reverse voltage and 5.0 peak gate voltage and 1.3 on-state voltage, **Current Rating Per Characteristic:** 165.00 amperes drain current megawatts and 10.50 amperes collector current, dc major **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf Shelf Life: N/a **Unit Of Measure:** Demilitarization: Yes - demil/mli Fiig: